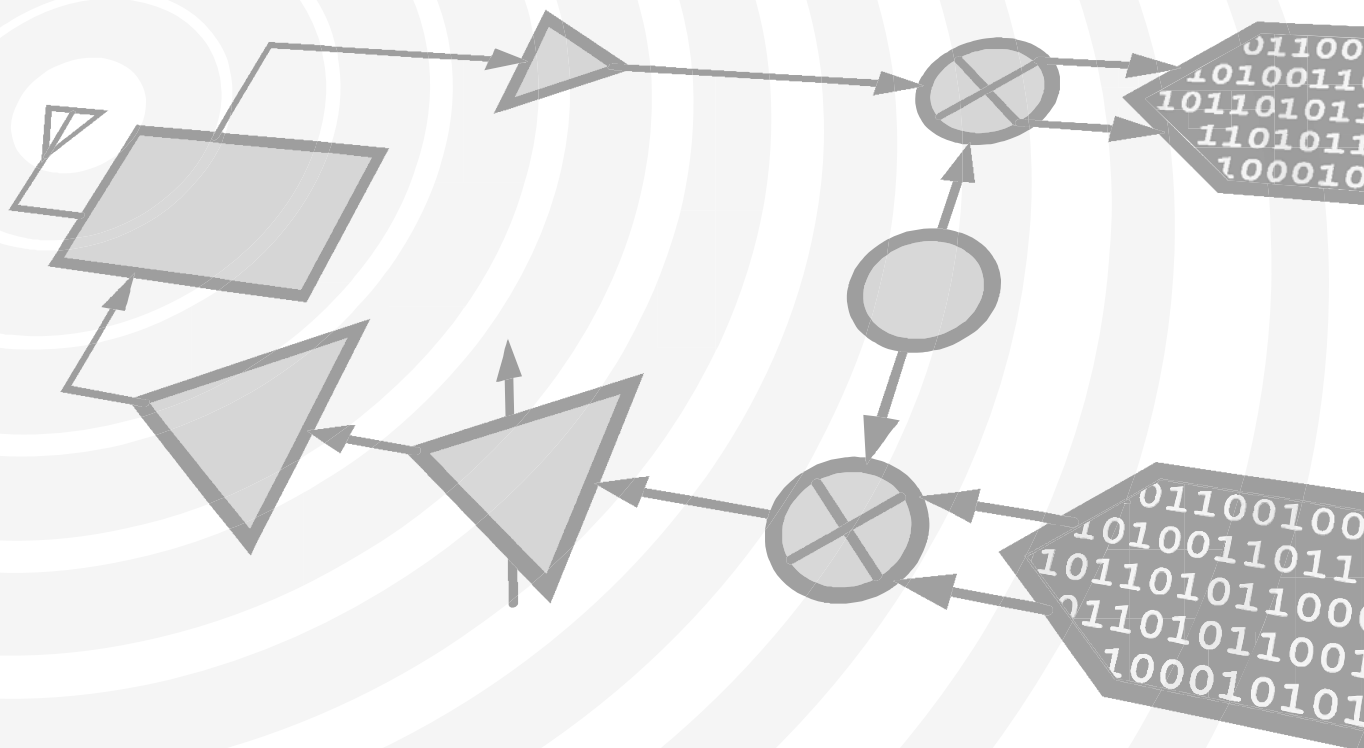




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MICROWAVE CORPORATION v03.0514



HMC578LC3B

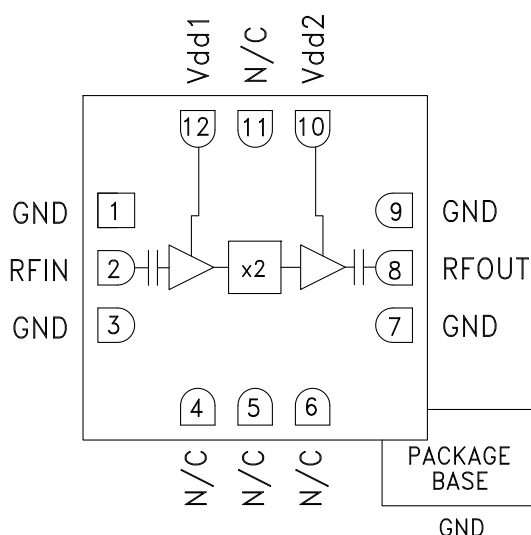
SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz

Typical Applications

The HMC578LC3B is suitable for:

- Clock Generation Applications:
SONET OC-192 & SDH STM-64
- Point-to-Point & VSAT Radios
- Test Instrumentation
- Military & Space

Functional Diagram



Features

- High Output Power: +15 dBm
- Low Input Power Drive: 0 to +6 dBm
- Fo Isolation: >20 dBc @ Fout= 28 GHz
- 100 KHz SSB Phase Noise: -132 dBc/Hz
- Single Supply: +5V@ 81 mA
- RoHS Compliant 3x3 mm SMT Package

General Description

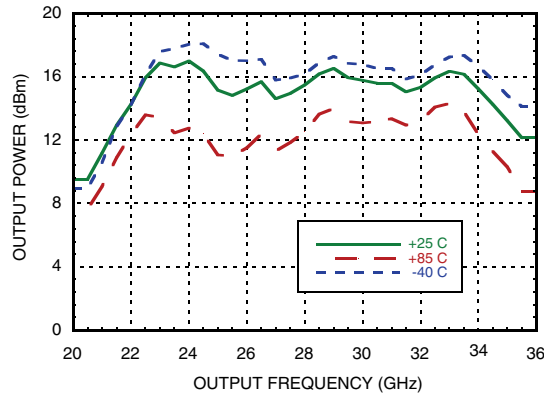
The HMC578LC3B is a x2 active broadband frequency multiplier utilizing GaAs PHEMT technology in a leadless RoHS compliant SMT package. When driven by a +3 dBm signal, the multiplier provides +15 dBm typical output power from 23 to 33 GHz. The Fo and 3Fo isolations are >20 dBc and >30 dBc respectively at 28 GHz. The HMC578LC3B is ideal for use in LO multiplier chains for Pt-to-Pt & VSAT Radios yielding reduced parts count vs. traditional approaches. The low additive SSB Phase Noise of -129 dBc/Hz at 100 kHz offset helps maintain good system noise performance. The RoHS packaged HMC578LC3B eliminates the need for wire bonding, and allows the use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^\circ \text{C}$, V_{dd1} , $V_{dd2} = +5\text{V}$, 3 dBm Drive Level

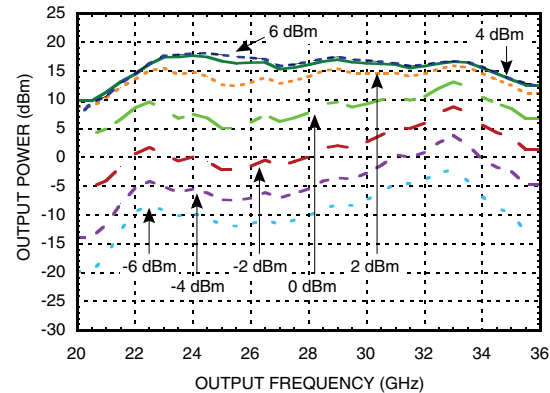
Parameter	Min.	Typ.	Max.	Units
Frequency Range, Input	11.5 - 16.5			GHz
Frequency Range, Output	23 - 33			GHz
Output Power	10	15		dBm
Fo Isolation (with respect to output level)		20		dBc
3Fo Isolation (with respect to output level)		30		dBc
Input Return Loss		10		dB
Output Return Loss		12		dB
SSB Phase Noise (100 kHz Offset)		-132		dBc/Hz
Supply Current (Idd1 & Idd2)		81		mA

SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz

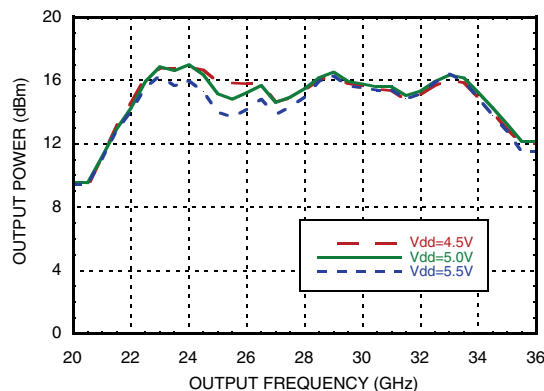
Output Power vs. Temperature @ 3 dBm Drive Level



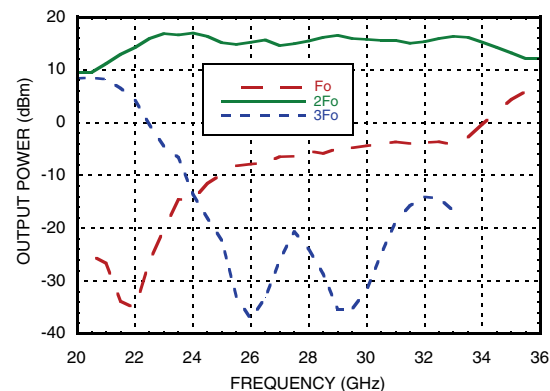
Output Power vs. Drive Level



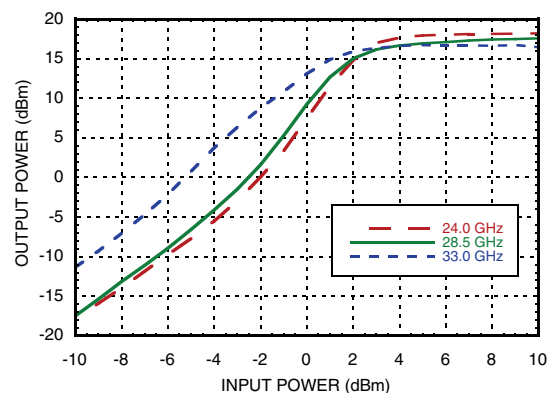
Output Power vs. Supply Voltage @ 3 dBm Drive Level



Isolation @ 3 dBm Drive Level

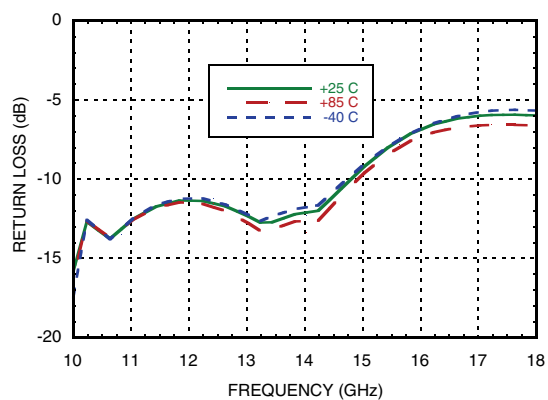
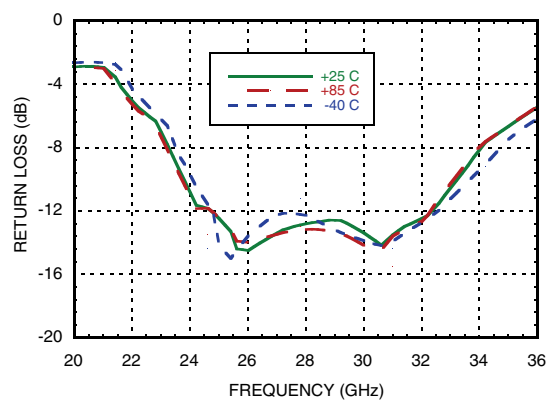


Output Power vs. Input Power





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**HMC578LC3B****SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 23 - 33 GHz****Input Return Loss vs. Temperature****Output Return Loss vs. Temperature**

**SMT GaAs MMIC x2 ACTIVE FREQUENCY
MULTIPLIER, 23 - 33 GHz**
Absolute Maximum Ratings

RF Input (Vdd = +5V)	+13 dBm
Supply Voltage (Vdd)	+6.0 Vdc
Channel Temperature	175 °C
Continuous Pdiss (T= 85 °C) (derate 7.4 mW/°C above 85 °C)	670 mW
Thermal Resistance (channel to ground paddle)	135 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C

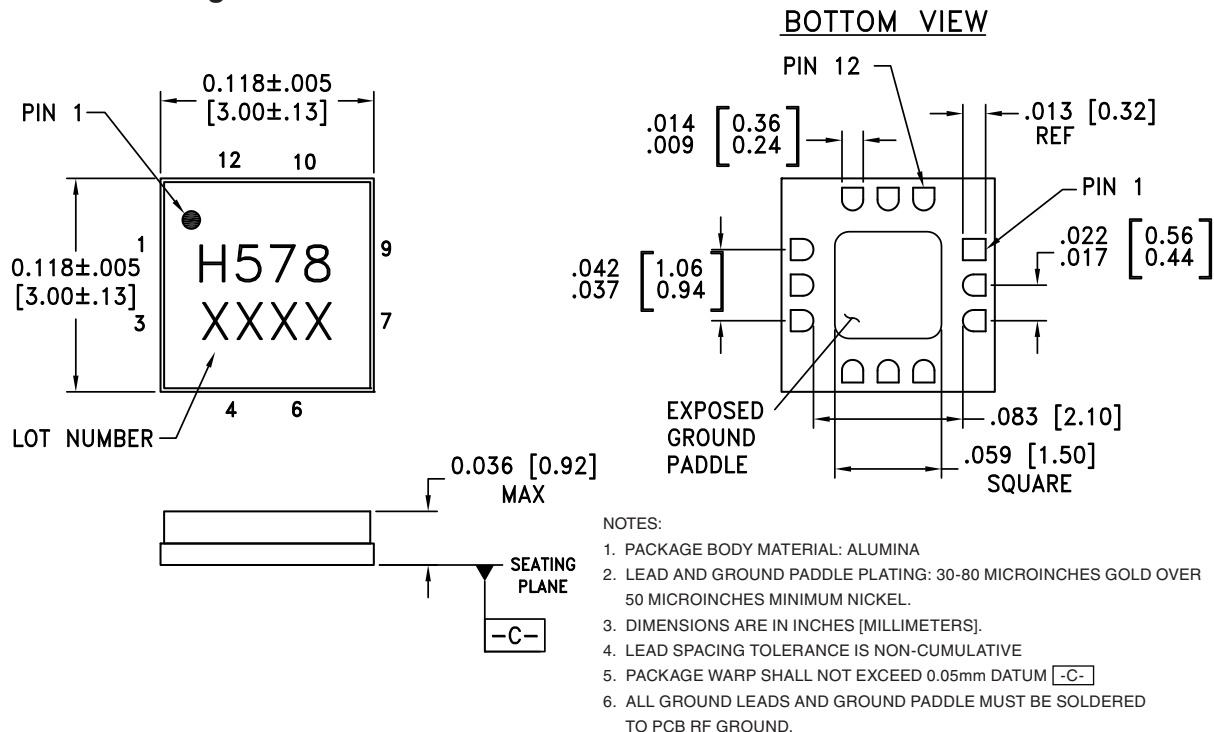
Typical Supply Current vs. Vdd

Vdd (Vdc)	Idd (mA)
4.5	81
5.0	81
5.5	81

Note:
Multiplier will operate over full voltage range shown above.



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

Outline Drawing

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC578LC3B	Alumina, White	Gold over Nickel	MSL3 ^[1]	H578 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

For price, delivery and to place orders: Hittite Microwave Corporation, 2 Elizabeth Drive, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com



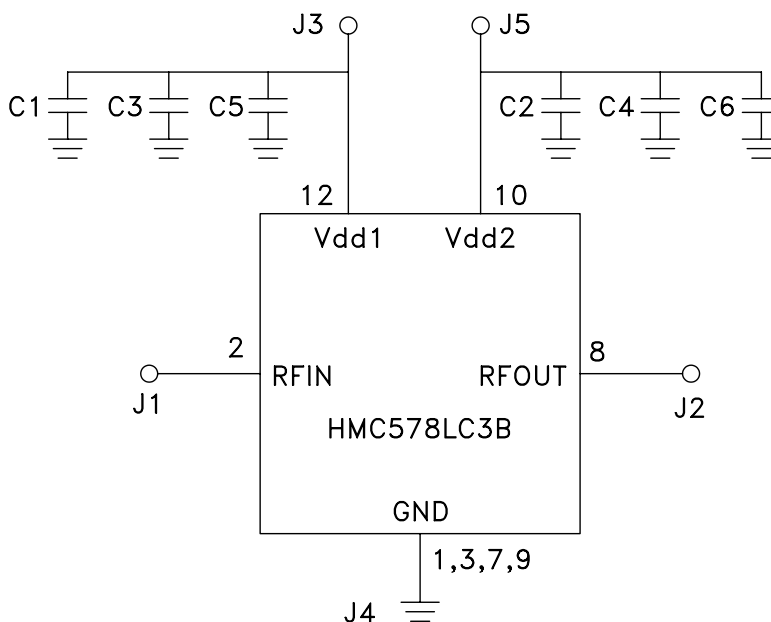
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**HMC578LC3B****SMT GaAs MMIC x2 ACTIVE FREQUENCY MULTIPLIER, 23 - 33 GHz****Pin Description**

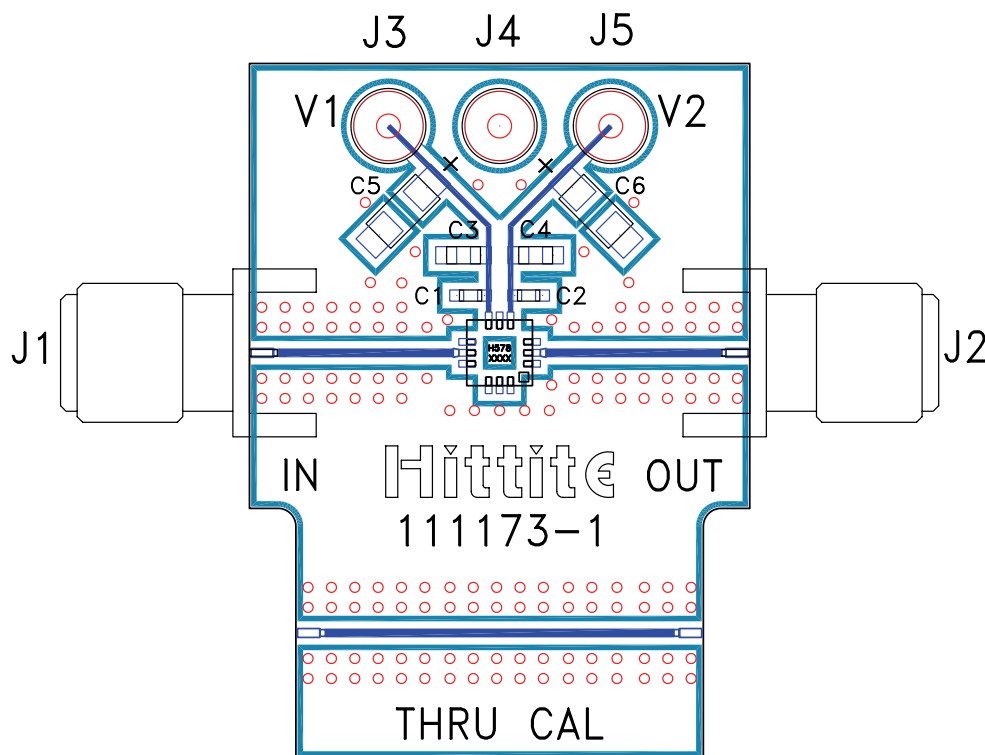
Pin Number	Function	Description	Interface Schematic
1, 3, 7, 9	GND	Package bottom must also be connected to RF/DC ground.	
2	RFIN	Pin is AC coupled and matched to 50 Ohms.	
4 - 6, 11	N/C	These pins are internally not connected; however, this product was specified with these pins connected to RF/DC ground.	
8	RFOUT	Pin is AC coupled and matched to 50 Ohms.	
10, 12	Vdd2, Vdd1	Supply voltage 5V $\pm$ 0.5V. External bypass capacitors of 100 pF, 1,000 pF and 2.2 μ F are required.	

Application Circuit

Component	Value
C1, C2	100 pF
C3, C4	1,000 pF
C5, C6	2.2 μ F



Evaluation PCB



List of Materials for Evaluation PCB 112409 ^[1]

Item	Description
J1, J2	PCB Mount SRI K Connector
J3 - J5	DC Pin
C1, C2	100 pF Capacitor, 0402 Pkg.
C3, C4	1,000 pF Capacitor, 0603 Pkg.
C5, C6	2.2 μ F Tantalum Capacitor
U1	HMC578LC3B x2 Active Multiplier
PCB [2]	111173 Eval Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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<http://moschip.ru/get-element>

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